Low Voltage Single Supply Dual DPDT Analog Switch

The NLAS44599 is an advanced dual-independent CMOS double pole-double throw (DPDT) analog switch fabricated with silicon gate CMOS technology. It achieves high speed propagation delays and low ON resistances while maintaining CMOS low power dissipation. This DPDT controls analog and digital voltages that may vary across the full power-supply range (from V_{CC} to GND).

The device has been designed so the ON resistance (R_{ON}) is much lower and more linear over input voltage than R_{ON} of typical CMOS analog switches.

The channel select input is compatible with standard CMOS outputs.

The channel select input structure provides protection when voltages between 0 V and 5.5 V are applied, regardless of the supply voltage. This input structure helps prevent device destruction caused by supply voltage – input/output voltage mismatch, battery backup, hot insertion, etc.

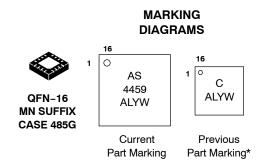
The NLAS44599 can also be used as a quad 2-to-1 multiplexerdemultiplexer analog switch with two Select pins that each controls two multiplexer-demultiplexers.

- Channel Select Input Over-Voltage Tolerant to 5.5 V
- Fast Switching and Propagation Speeds
- Break-Before-Make Circuitry
- Low Power Dissipation: $I_{CC} = 2 \mu A$ (Max) at $T_A = 25^{\circ}C$
- Diode Protection Provided on Channel Select Input
- Improved Linearity and Lower ON Resistance over Input Voltage
- Latch-up Performance Exceeds 300 mA
- ESD Performance: Human Body Model; > 2000 V, Machine Model; > 200 V
- Chip Complexity: 158 FETs
- Pb-Free Packages are Available

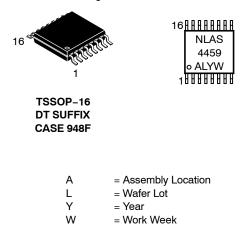


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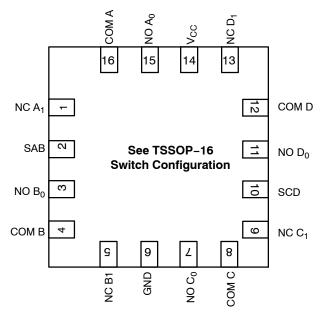
*Previous releases of this device may be marked as shown in this diagram.



ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 10 of this data sheet.

QFN-16 PACKAGE



NO A₀

COM A

NC A₁

NO B_0

COM B

NC B₁

GND

SELECT AB

1

2

3

4

5

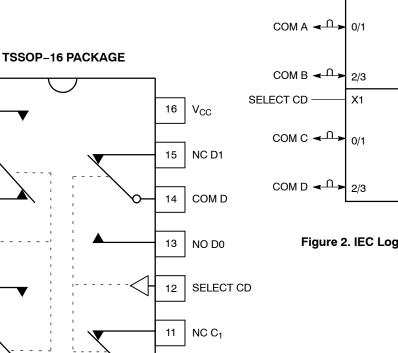
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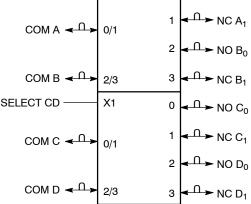
8

FUNCTION TABLE

Select AB or CD	On Channel
L H	NC to COM NO to COM



SELECT AB -



X1

Figure 2. IEC Logic Symbol

Figure 1. Logic Diagram

10

9

сом с

NO C₀

MAXIMUM RATINGS

Symbol	Par	ameter	Value	Unit
V _{CC}	Positive DC Supply Voltage		-0.5 to +7.0	V
V _{IS}	Analog Input Voltage (V_{NO} or V_{COM})		$-0.5 \leq V_{IS} \leq V_{CC} + 0.5$	
V _{IN}	Digital Select Input Voltage	$-0.5 \leq V_{I} \leq +7.0$	V	
I _{IK}	DC Current, Into or Out of Any Pin	±50	mA	
P _D	Power Dissipation in Still Air	800 450	mW	
T _{STG}	Storage Temperature Range	- 65 to + 150	°C	
TL	Lead Temperature, 1 mm from Case for 1	260	°C	
TJ	Junction Temperature Under Bias		+150	°C
MSL	Moisture Sensitivity		Level 1	
F _R	Flammability Rating	Oxygen Index: 30% – 35%	UL 94–V0 (0.125 in)	
V _{ESD}	ESD Withstand Voltage	Human Body Model (Note 1) Machine Model (Note 2) Charged Device Model (Note 3)	2000 200 1000	V
I _{Latch-Up}	Latch–Up Performance A	bove V_{CC} and Below GND at 125°C (Note 4)	±300	mA
θ_{JA}	Thermal Resistance	QFN-16 TSSOP-16	80 164	°C/W

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. Tested to EIA/JESD22-A114-A.

2. Tested to EIA/JESD22-A115-A.

3. Tested to JESD22-C101-A.

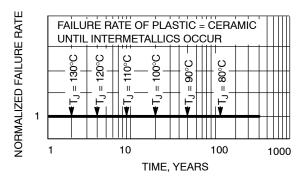
4. Tested to EIA/JESD78.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Min	Max	Unit	
V _{CC}	DC Supply Voltage	2.0	5.5	V	
V _{IN}	Digital Select Input Voltage	GND	5.5	V	
V _{IS}	Analog Input Voltage (NC, NO, COM)	GND	V _{CC}	V	
T _A	Operating Temperature Range		- 55	+125	°C
t _r , t _f	Input Rise or Fall Time, SELECT Vo	$C_{C} = 3.3 \text{ V} \pm 0.3 \text{ V}$ $C_{C} = 5.0 \text{ V} \pm 0.5 \text{ V}$	0 0	100 20	ns/V

DEVICE JUNCTION TEMPERATURE VERSUS TIME TO 0.1% BOND FAILURES

Junction Temperature °C	Time, Hours	Time, Years
80	1,032,200	117.8
90	419,300	47.9
100	178,700	20.4
110	79,600	9.4
120	37,000	4.2
130	17,800	2.0
140	8,900	1.0





				Guaranteed Limit			
Symbol	Parameter	Condition	V _{cc}	-55°C to 25°C	<85°C	<125°C	Unit
V _{IH}	Minimum High–Level Input		2.0	1.5	1.5	1.5	V
	Voltage, Select Inputs		2.5	1.9	1.9	1.9	
			3.0	2.1	2.1	2.1	
			4.5	3.15	3.15	3.15	
			5.5	3.85	3.85	3.85	
V _{IL}	Maximum Low-Level Input		2.0	0.5	0.5	0.5	V
	Voltage, Select Inputs		2.5	0.6	0.6	0.6	
			3.0	0.9	0.9	0.9	
			4.5	1.35	1.35	1.35	
			5.5	1.65	1.65	1.65	
I _{IN}	Maximum Input Leakage Current	V _{IN} = 5.5 V or GND	5.5	±0.2	±2.0	±2.0	μA
I _{OFF}	Power Off Leakage Current, Select Inputs	V _{IN} = 5.5 V or GND	0	±10	±10	±10	μA
Icc	Maximum Quiescent Supply Current	Select and $V_{IS} = V_{CC}$ or GND	5.5	4.0	4.0	8.0	μA

DC CHARACTERISTICS - Digital Section (Voltages Referenced to GND)

DC ELECTRICAL CHARACTERISTICS – Analog Section

				Guaranteed Limit			
Symbol	Parameter	Condition	V _{CC}	-55°C to 25°C	<85°C	<125°C	Unit
R _{ON}	Maximum "ON" Resistance	V _{IN} = V _{IL} or V _{IH}	2.5	85	95	105	Ω
	(Figures 17 – 23)	$V_{IS} = GND$ to V_{CC}	3.0	45	50	55	
		$I_{IN}I \leq 10.0 \text{ mA}$	4.5	30	35	40	
			5.5	25	30	35	
R _{FLAT (ON)}	ON Resistance Flatness (Figures 17 – 23)	$\begin{array}{l} V_{IN} = V_{IL} \text{ or } V_{IH} \\ I_{IN}I \leq 10.0 \text{ mA} \\ V_{IS} = 1 \text{V}, 2 \text{V}, 3.5 \text{V} \end{array}$	4.5	4	4	5	Ω
I _{NC(OFF)} I _{NO(OFF)}	NO or NC Off Leakage Current (Figure 9)	$V_{IN} = V_{IL} \text{ or } V_{IH}$ V _{NO} or V _{NC} = 1.0 V _{COM} 4.5 V	5.5	1	10	100	nA
I _{COM(ON)}	COM ON Leakage Current (Figure 9)	$\label{eq:VIN} \begin{array}{l} V_{IN} = V_{IL} \mbox{ or } V_{IH} \\ V_{NO} \ 1.0 \ V \mbox{ or } 4.5 \ V \ \mbox{with } V_{NC} \ \mbox{floating or } \\ V_{NO} \ 1.0 \ \ \ \mbox{ or } 4.5 \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \$	5.5	1	10	100	nA

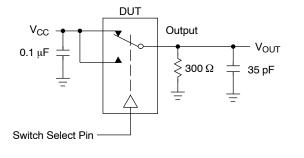
AC ELECTRICAL CHARACTERISTICS (Input $t_r = t_f = 3.0$ ns)

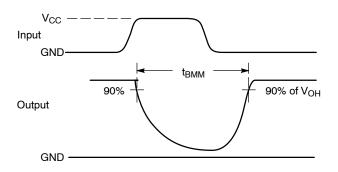
						Guaranteed Maximum Limit						
			v _{cc}	VIS	- 5	5°C to 2	25°C	<85°C <12		125°C		
Symbol	Parameter	Test Conditions	(V)	(V)	Min	Тур*	Max	Min	Max	Min	Max	Unit
t _{ON}	Turn-On Time	$R_L = 300 \Omega, C_L = 35 pF$	2.5	2.0	5	23	35	5	38	5	41	ns
	(Figures 12 and 13)	(Figures 5 and 6)	3.0	2.0	5	16	24	5	27	5	30	
			4.5	3.0	2	11	16	2	19	2	22	
			5.5	3.0	2	9	14	2	17	2	20	
t _{OFF}	Turn–Off Time	$R_L = 300 \Omega, C_L = 35 pF$	2.5	2.0	1	7	12	1	15	1	18	ns
	(Figures 12 and 13)	(Figures 5 and 6)	3.0	2.0	1	5	10	1	13	1	16	
			4.5	3.0	1	4	6	1	9	1	12	
			5.5	3.0	1	3	5	1	8	1	11	
t _{BBM}	Minimum Break-Before-Make	V _{IS} = 3.0 V (Figure 4)	2.5	2.0	1	12		1		1		ns
	Time	R_L = 300 Ω , C_L = 35 pF	3.0	2.0	1	11		1		1		
			4.5	3.0	1	6		1		1		
			5.5	3.0	1	5		1		1		
		Typical @ 25, V _{CC} = 5.0 V						_				
C _{IN}	IN Maximum Input Capacitance, Select Input						8					pF
C _{NO} or C	· ·						10					
C _{COM}	Common I/O (switch off)						10					
C _(ON)	Feedthrough (switch on)						20					

*Typical Characteristics are at 25°C.

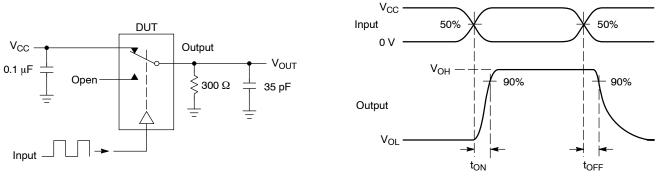
ADDITIONAL APPLICATION CHARACTERISTICS (Voltages Referenced to GND Unless Noted)

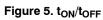
			V _{CC}	Typical	
Symbol	Parameter	meter Condition		25°C	Unit
BW	Maximum On-Channel -3dB	V _{IN} = 0 dBm	3.0	145	MHz
	Bandwidth or Minimum Frequency Response (Figure 11)	V_{IN} centered between V_{CC} and GND	4.5	170	
		(Figure 7)	5.5	175	
V _{ONL}	Maximum Feedthrough On Loss	V _{IN} = 0 dBm @ 100 kHz to 50 MHz	3.0	-3	dB
		V _{IN} centered between V _{CC} and GND	4.5	-3	
		(Figure 7)	5.5	-3	
V _{ISO}	Off-Channel Isolation (Figure 10)	f = 100 kHz; V _{IS} = 1 V RMS	3.0	-93	dB
		V _{IN} centered between V _{CC} and GND	4.5	-93	
		(Figure 7)	5.5	-93	
Q	Charge Injection Select Input to	V _{IN =} V _{CC to} GND, F _{IS} = 20 kHz			рС
	Common I/O (Figure 15)	$t_r = t_f = 3 \text{ ns}$	3.0	1.5	
		$R_{IS} = 0 \ \Omega, \ C_L = 1000 \ pF$	5.5	3.0	
		$Q = C_L * \Delta V_{OUT}$			
		(Figure 8)			
THD	Total Harmonic Distortion THD +	F_{IS} = 20 Hz to 100 kHz, R_{L} = Rgen = 600 $\Omega,$ C_{L} = 50 pF			%
	Noise (Figure 14)	$V_{IS} = 5.0 V_{PP}$ sine wave	5.5	0.1	
VCT	Channel-to-Channel Crosstalk	f = 100 kHz; V _{IS} = 1 V RMS			dB
		V_{IN} centered between V_{CC} and GND	5.5	-90	
		(Figure 7)	3.0	-90	

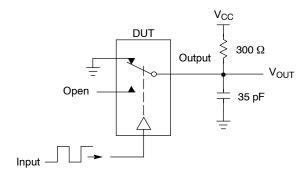


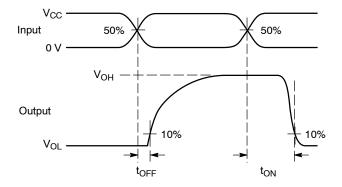


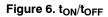


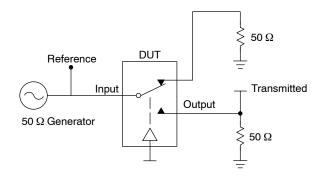








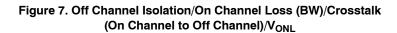


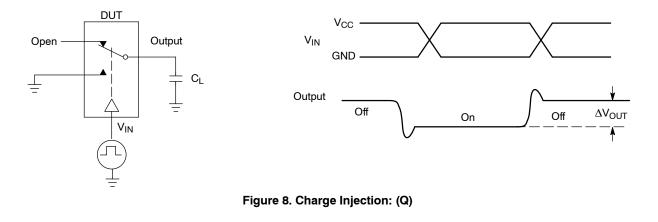


Channel switch control/s test socket is normalized. Off isolation is measured across an off channel. On loss is the bandwidth of an On switch. V_{ISO} , Bandwidth and V_{ONL} are independent of the input signal direction.

$$\begin{split} V_{ISO} &= \text{Off Channel Isolation} = 20 \text{ Log } \left(\frac{V_{OUT}}{V_{IN}}\right) &\text{for } V_{IN} \text{ at } 100 \text{ kHz} \\ V_{ONL} &= \text{On Channel Loss} = 20 \text{ Log } \left(\frac{V_{OUT}}{V_{IN}}\right) &\text{for } V_{IN} \text{ at } 100 \text{ kHz} \text{ to } 50 \text{ MHz} \end{split}$$

Bandwidth (BW) = the frequency 3 dB below V_{ONL} V_{CT} = Use V_{ISO} setup and test to all other switch analog input/outputs terminated with 50 Ω





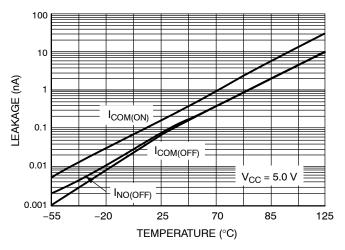
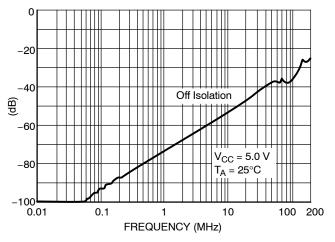
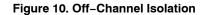
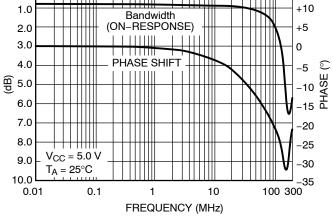


Figure 9. Switch Leakage vs. Temperature

0







+15



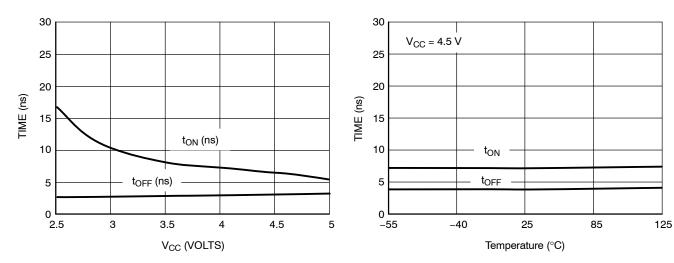
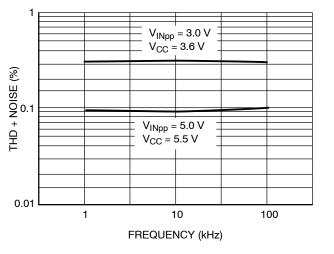
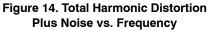
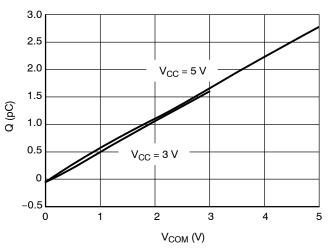


Figure 12. t_{ON} and t_{OFF} vs. V_{CC} at 25 $^\circ C$

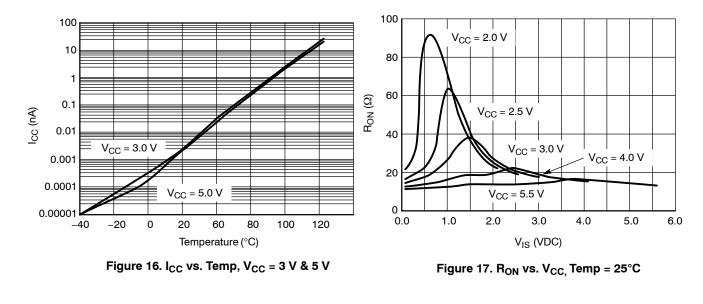


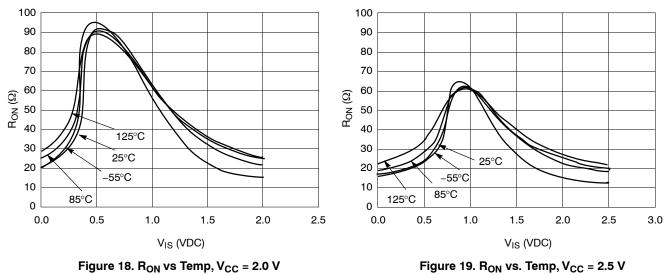












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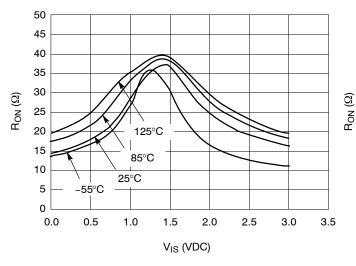
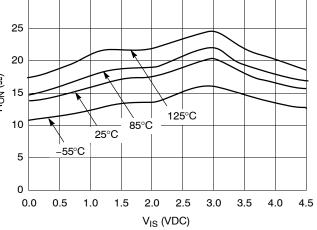
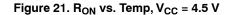


Figure 20. R_{ON} vs. Temp, V_{CC} = 3.0 V







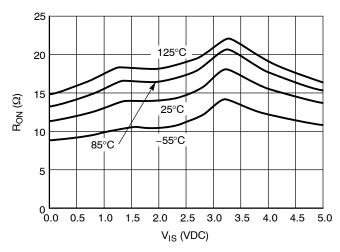


Figure 22. R_{ON} vs. Temp, V_{CC} = 5.0 V

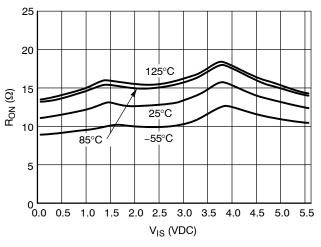


Figure 23. R_{ON} vs. Temp, V_{CC} = 5.5 V

DEVICE ORDERING INFORMATION

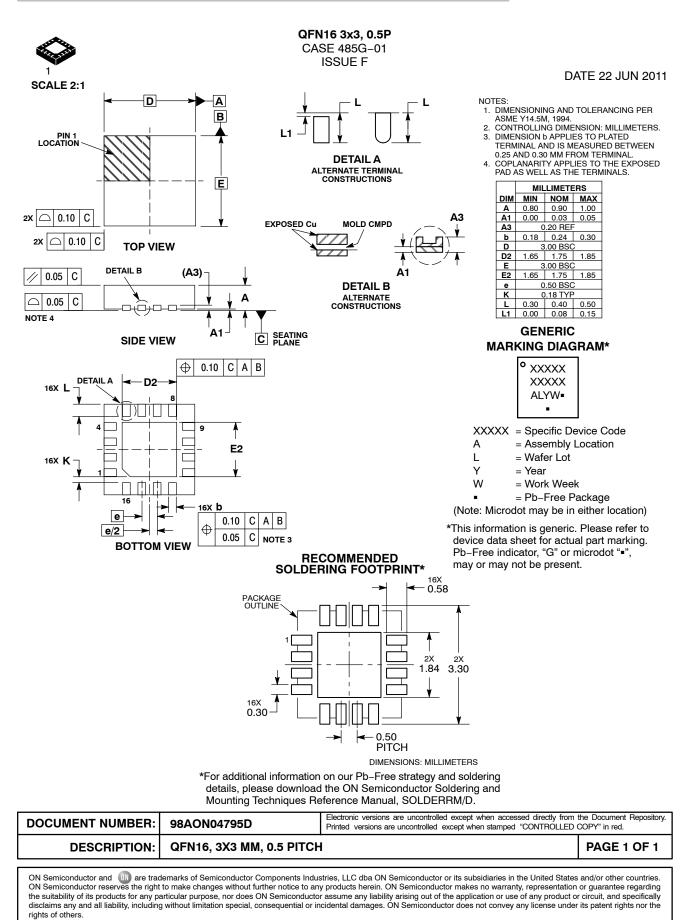
	Device Nomenclature						
Device	Circuit Indicator	Technology	Device Function	Package Suffix	Tape & Reel Suffix	Package Type	Shipping [†]
NLAS44599DT	NL	AS	44599	DT		TSSOP-16*	96 / Unit Rail
NLAS44599DTR2	NL	AS	44599	DT	R2	TSSOP-16*	2500 / Tape & Reel
NLAS44599MN	NL	AS	44599	MN		QFN-16	124 Unit / Rail
NLAS44599MNG	NL	AS	44599	MN		QFN-16 (Pb-Free)	124 Unit / Rail
NLAS44599MNR2	NL	AS	44599	MN	R2	QFN-16	2500 / Tape & Reel
NLAS44599MNR2G	NL	AS	44599	MN	R2	QFN-16 (Pb-Free)	2500 / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

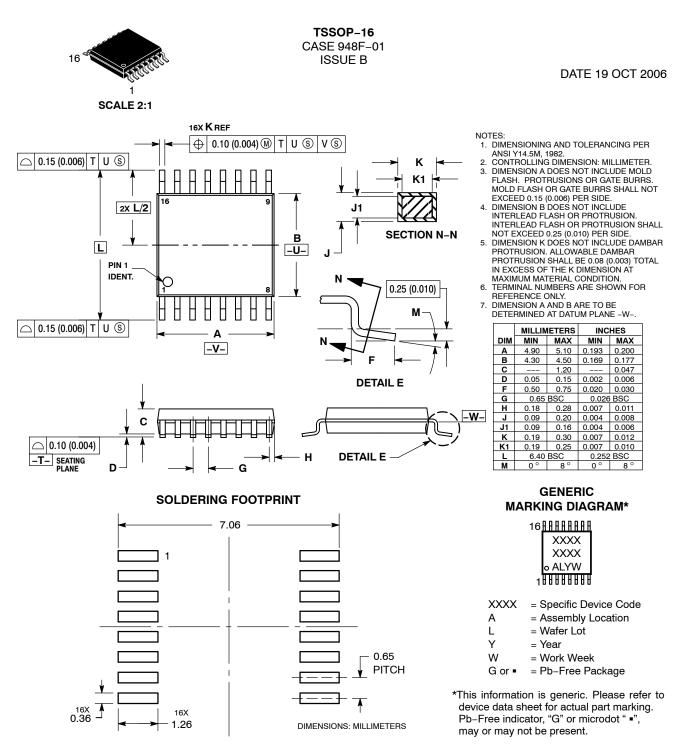
*This package is inherently Pb-Free.

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